TOSHIBA Field Effect Transistor Silicon P Channel Junction Type

# 2SJ108

## Low Noise Audio Amplifier Applications

Unit: mm

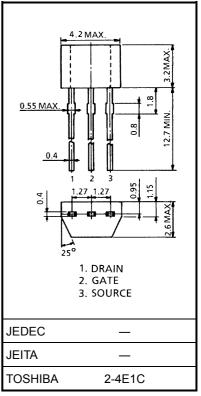
- Recommended for first stages of EQ amplifiers and MC head amplifiers.
- High  $|Y_{fs}|$ :  $|Y_{fs}| = 22$  mS (typ.)  $(V_{DS} = -10 \text{ V}, V_{GS} = 0, I_{DSS} = -3 \text{ mA})$
- Low noise: En =  $0.95 \text{ nV/Hz}^{1/2}$  (typ.)

$$(V_{DS} = -10 \text{ V}, I_{D} = -1 \text{ mA}, f = 1 \text{ kHz})$$

- High input impedance:  $I_{GSS} = 1.0 \text{ nA (max) (V}_{GS} = 25 \text{ V)}$
- Complementary to 2SK370
- Small package

### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	$V_{GDS}$	25	V
Gate current	I <sub>G</sub>	-10	mA
Drain power dissipation	$P_{D}$	200	mW
Junction temperature	Tj	125	°C
Storage temperature range	T <sub>stg</sub>	-55~125	°C

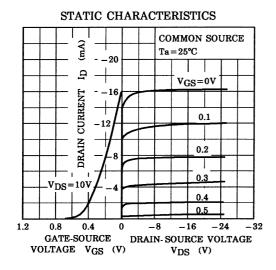


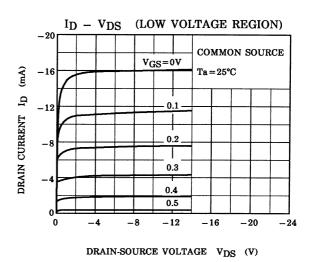
Weight: 0.13 g (typ.)

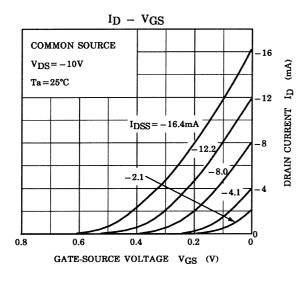
# **Electrical Characteristics (Ta = 25°C)**

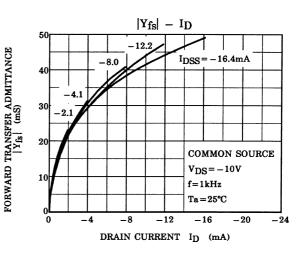
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I <sub>GSS</sub>	$V_{GS} = 25 \text{ V}, V_{DS} = 0$	_	_	1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0$ , $I_G = 100 \mu A$	25	_	_	V
Drain current	I <sub>DSS</sub> (Note)	$V_{DS} = -10 \text{ V}, V_{GS} = 0$	-2.6	_	-20	mA
Gate-source cut-off voltage	V <sub>GS</sub> (OFF)	$V_{DS} = -10 \text{ V}, I_D = -0.1 \mu\text{A}$	0.15	_	2.0	V
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$	8	22	_	mS
Input capacitance	C <sub>iss</sub>	$V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	_	105	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	$V_{GD} = 10 \text{ V}, I_D = 0, f = 1 \text{ MHz}$	_	32	_	pF
Noise figure	NF (1)	$\begin{split} V_{DS} = -10 \text{ V, I}_D = -1 \text{ mA, R}_G = 1 \text{ k}\Omega, \\ f = 10 \text{ Hz} \end{split}$	_	1.0	10	- dB
	NF (2)	$\begin{split} V_{DS} = -10 \text{ V, I}_D = -1 \text{ mA, R}_G = 1 \text{ k}\Omega, \\ f = 1 \text{ kHz} \end{split}$	_	0.5	2	uБ

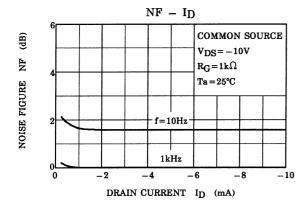
Note:  $I_{DSS}$  classification GR: -2.6~-6.5 mA, BL: -6.0~-12 mA, V: -10~-20 mA

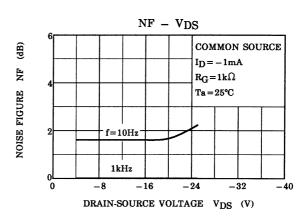




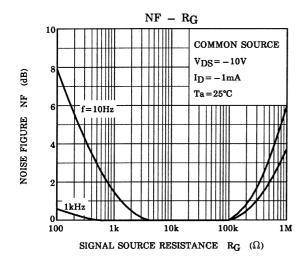


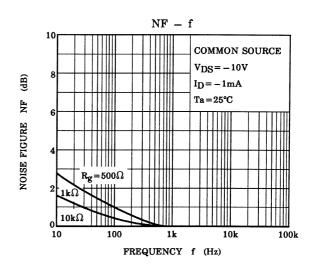


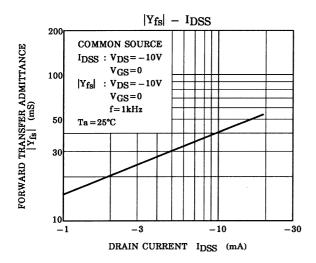


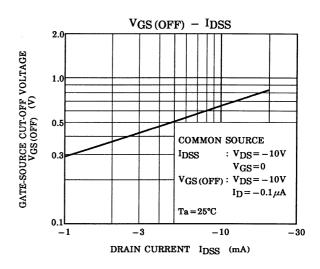


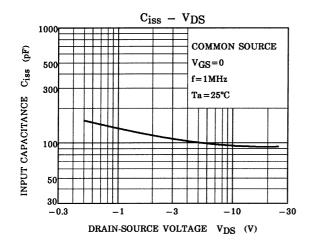
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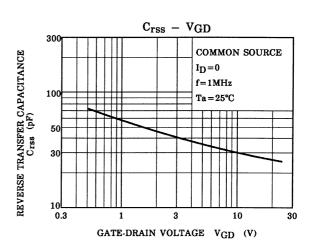




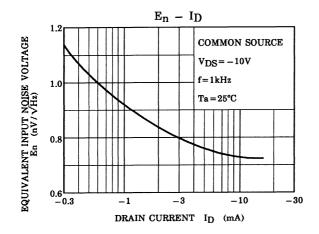


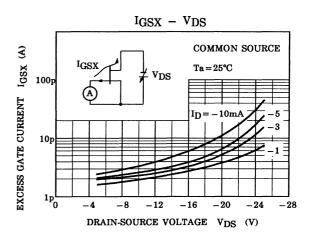


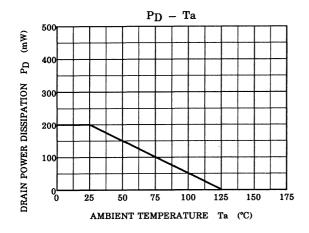




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